

TPCP8504

High Speed Switching Applications

DC-DC Converter Applications

- High DC current gain : $h_{FE} = 400$ to 1000 ($I_C = 0.2$ A)
- Low collector-emitter saturation : $V_{CE(sat)} = 0.12$ V (max)
- High-speed switching : $t_f = 25$ ns (typ.)

Maximum Ratings ($T_a = 25^\circ\text{C}$)

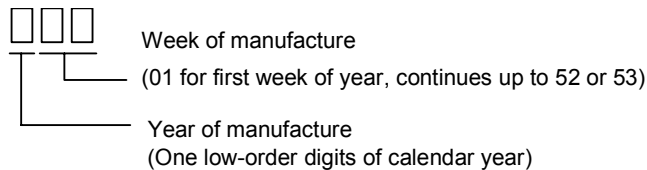
Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	20	V
Collector-emitter voltage		V_{CEO}	10	V
Emitter-base voltage		V_{EBO}	7	V
Collector current	DC (Note 1)	I_C	2.0	A
	Pulse (Note 1)	I_{CP}	3.5	
Base current		I_B	0.2	A
Collector power dissipation (Note 2)	$t = 10$ s	P_C	2.8	W
	DC		1.2	
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

Note 1: Please use devices on condition that the junction temperature is below 150°C .

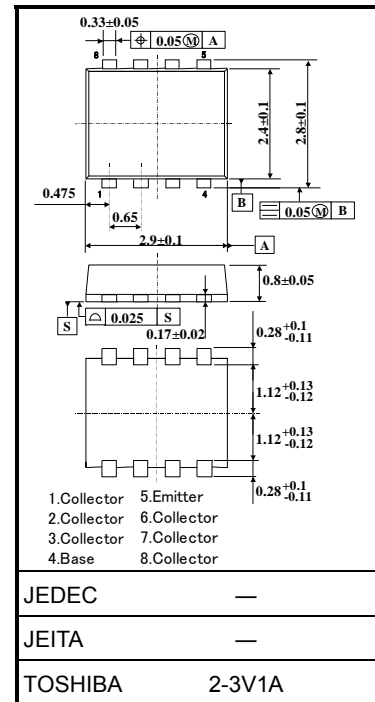
Note 2: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm^2)

Note 3: ● on lower left on the marking indicates Pin 1.

※ Weekly code: (Three digits)



Unit: mm



Weight: 0.017 g (typ.)

Figure 1.
Circuit configuration
(Top View)

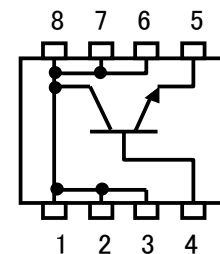
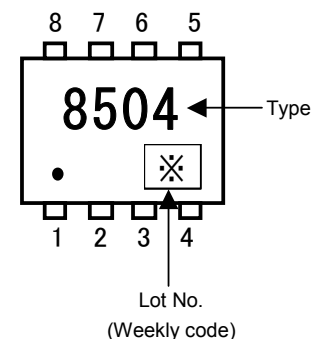


Figure 2. Marking
(Note 3)

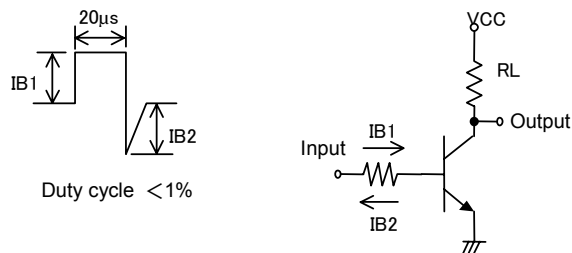


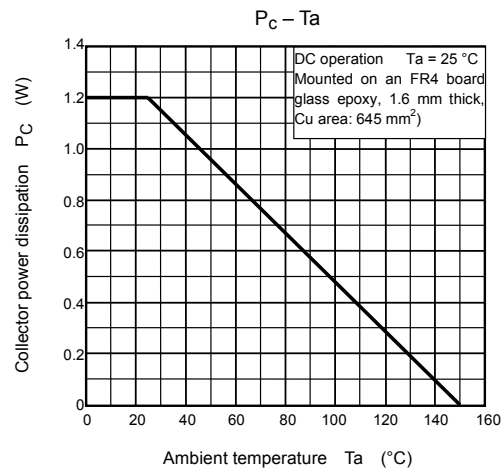
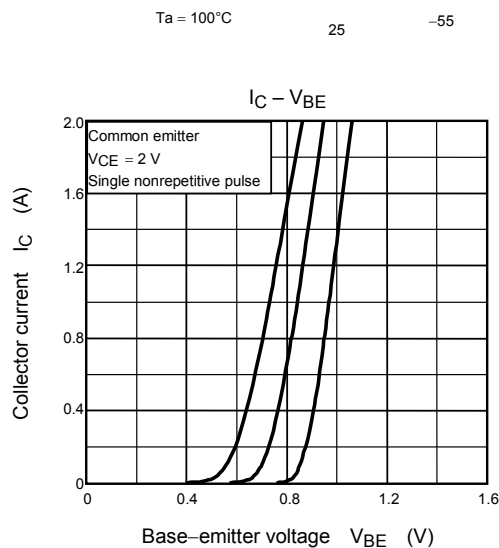
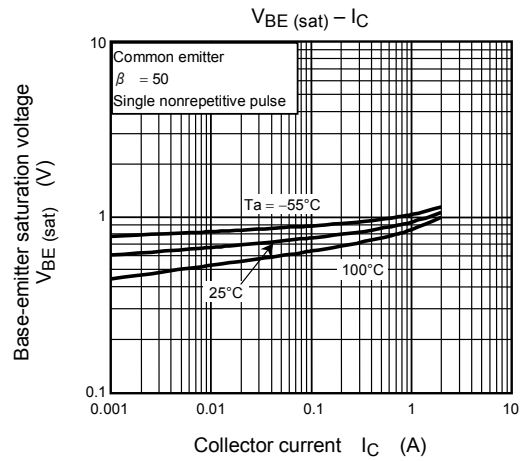
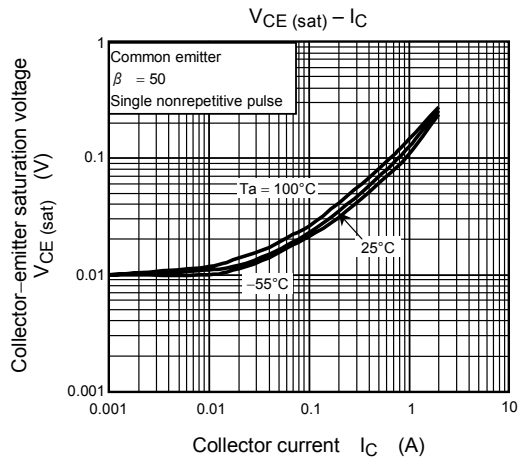
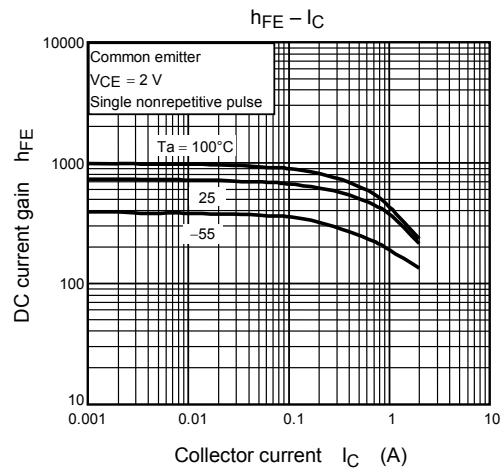
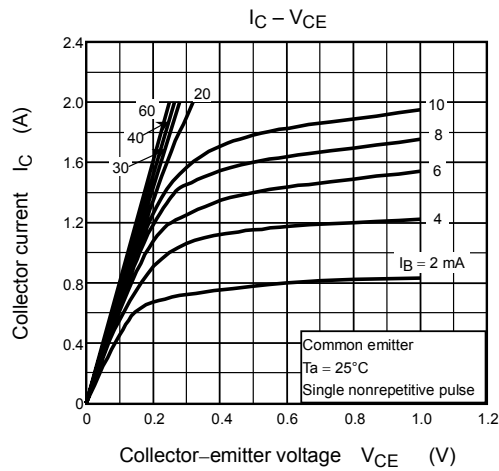
Electrical Characteristics (Ta = 25°C)

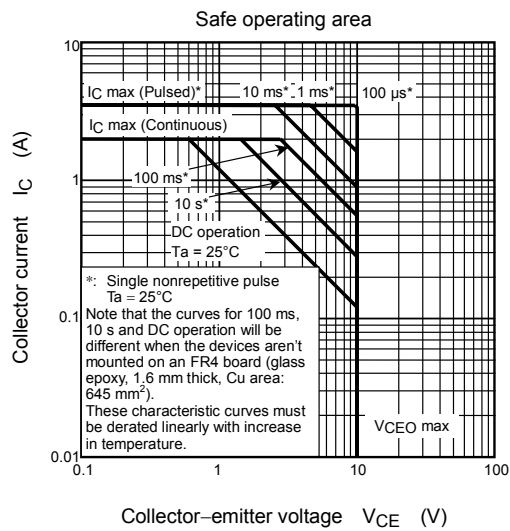
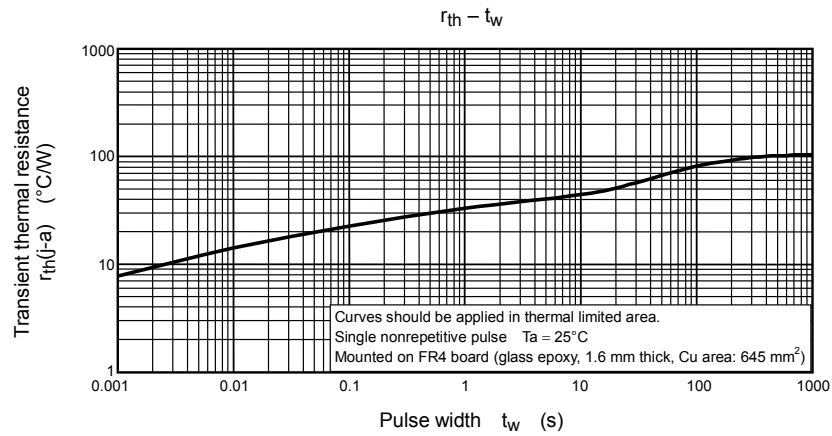
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Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	$V_{CB} = 20\text{ V}, I_E = 0$	—	—	100	nA
Emitter cut-off current		I_{EBO}	$V_{EB} = 7\text{ V}, I_C = 0$	—	—	100	nA
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = 10\text{ mA}, I_B = 0$	10	—	—	V
DC current gain		$h_{FE}(1)$	$V_{CE} = 2\text{ V}, I_C = 0.2\text{ A}$	400	—	1000	
		$h_{FE}(2)$	$V_{CE} = 2\text{ V}, I_C = 0.6\text{ A}$	200	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 0.6\text{ A}, I_B = 12\text{ mA}$	—	—	0.12	V
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = 0.6\text{ A}, I_B = 12\text{ mA}$	—	—	1.1	V
Collector output capacitance		C_{ob}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	10	—	pF
Switching time	Rise time	t_r	See Figure 3 circuit diagram $V_{CC} \approx 6\text{ V}, R_L = 10\ \Omega$ $I_{B1} = -I_{B2} = 12\text{ mA}$	—	60	—	ns
	Storage time	t_{stg}		—	215	—	
	Fall time	t_f		—	25	—	

Figure 3. Switching Time Test Circuit & Timing Chart







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